## José Eduardo Padilha

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/4454209/publications.pdf

Version: 2024-02-01

32 papers

1,388 citations

471509 17 h-index 30 g-index

32 all docs 32 docs citations

times ranked

32

2174 citing authors

#	Article	IF	CITATIONS
1	van der Waals Heterostructure of Phosphorene and Graphene: Tuning the Schottky Barrier and Doping by Electrostatic Gating. Physical Review Letters, 2015, 114, 066803.	7.8	445
2	Nature and evolution of the band-edge states in <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"&gt;<mml:msub><mml:mi>MoS</mml:mi><mml:mn>2From monolayer to bulk. Physical Review B, 2014, 90, .</mml:mn></mml:msub></mml:math 	m <b>ā.⁄2</b> <td>ml:n<b>nsa</b>b&gt;</td>	ml:n <b>nsa</b> b>
3	Metal Chalcogenides Janus Monolayers for Efficient Hydrogen Generation by Photocatalytic Water Splitting. ACS Applied Nano Materials, 2019, 2, 890-897.	5.0	93
4	Directional dependence of the electronic and transport properties of 2D borophene and borophane. Physical Chemistry Chemical Physics, 2016, 18, 25491-25496.	2.8	92
5	Free-Standing Bilayer Silicene: The Effect of Stacking Order on the Structural, Electronic, and Transport Properties. Journal of Physical Chemistry C, 2015, 119, 3818-3825.	3.1	73
6	Two-dimensional van der Waals <i>p-n</i> junction of InSe/phosphorene. Physical Review B, 2017, 95, .	3.2	68
7	Quantum spin Hall effect on germanene nanorod embedded in completely hydrogenated germanene. Physical Review B, 2014, 89, .	3.2	57
8	Electronic and transport properties of structural defects in monolayer germanene: An ab initio investigation. Solid State Communications, 2016, 225, 38-43.	1.9	50
9	Layer-dependent band alignment of few layers of blue phosphorus and their van der Waals heterostructures with graphene. Physical Review B, 2018, 97, .	3.2	45
10	Energetics and stability of vacancies in carbon nanotubes. Solid State Communications, 2011, 151, 482-486.	1.9	42
11	Bilayer graphene dual-gate nanodevice: An <i>ab initio</i> simulation. Physical Review B, 2011, 84, .	3.2	36
12	Transport properties of single vacancies in nanotubes. Physical Review B, 2008, 77, .	3.2	35
13	xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"> <mml:msub><mml:mrow /&gt;<mml:mi>x</mml:mi></mml:mrow </mml:msub> Ge <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"&gt;<mml:msub><mml:mrow /&gt;<mml:mrow><mml:mn>1</mml:mn><mml:mo>a^²</mml:mo><mml:mi>x</mml:mi>x</mml:mrow><td>3.2</td><td>24 path sallov</td></mml:mrow </mml:msub></mml:math 	3.2	24 path sallov
14	Physical Review B, 2013, 88. Bilayer graphene on h-BN substrate: investigating the breakdown voltage and tuning the bandgap by electric field. Journal of Physics Condensed Matter, 2012, 24, 075301.	1.8	22
15	Directional Control of the Electronic and Transport Properties of Graphynes. Journal of Physical Chemistry C, 2014, 118, 18793-18798.	3.1	18
16	Fully and partially iodinated germanane as a platform for the observation of the quantum spin Hall effect. Physical Review B, $2016$ , $93$ , .	3.2	18
17	lxV curves of boron and nitrogen doping zigzag graphene nanoribbons. International Journal of Quantum Chemistry, 2011, 111, 1379-1386.	2.0	17
18	A new class of large band gap quantum spin hall insulators: 2D fluorinated group-IV binary compounds. Scientific Reports, 2016, 6, 26123.	3.3	17

#	Article	IF	Citations
19	Microscopic Description of the Ferroism in Lead-Free AlFeO3. Scientific Reports, 2018, 8, 6420.	3.3	17
20	Electronic and optical properties of hydrogenated group-IV multilayer materials. Physical Chemistry Chemical Physics, 2018, 20, 8112-8118.	2.8	12
21	Graphene nanoribbon intercalated with hexagonal boron nitride: Electronic transport properties from ab initio calculations. Solid State Communications, 2013, 173, 24-29.	1.9	10
22	Topological phase transitions of (BixSb1 $\hat{a}$ 'x)2Se3 alloys by density functional theory. Journal of Physics Condensed Matter, 2015, 27, 255501.	1.8	10
23	Stacking-dependent transport properties in few-layers graphene. Solid State Communications, 2017, 250, 70-74.	1.9	10
24	Tunable magnetism and spin-polarized electronic transport in graphene mediated by molecular functionalization of extended defects. Physical Review B, 2018, 97, .	3.2	9
25	Structural evolution and the role of native defects in subnanometer MoS nanowires. Physical Review B, 2019, 100, .	3.2	7
26	Green synthesis of templated carbon porous materials from simple raw materials. Materials Advances, 2021, 2, 403-412.	5.4	7
27	Interatomic potential for atomistic simulation of self-catalyzed GaAs nanowires growth. Computational Materials Science, 2020, 183, 109805.	3.0	5
28	Substrate-supported large-band-gap quantum spin Hall insulator based on III-V bismuth layers. Physical Review B, 2016, 94, .	3.2	4
29	Structural Transition in Oxidized Ca2N Electrenes: CaO/CaN 2D Heterostructures. Journal of Physical Chemistry C, 2020, 124, 14706-14712.	3.1	4
30	Electron density distribution and electronic structure as tools to study the origin of ferroic states in ferroelectric and magnetic materials. Ferroelectrics, 2016, 500, 26-36.	0.6	2
31	Oxidation of two-dimensional electrides: Structural transition and the formation of half-metallic channels protected by oxide layers. Physical Review B, 2022, 105, .	3.2	1
32	Nanodots of transition metal dichalcogenides embedded in MoS2 and MoSe2: first-principles calculations. Physical Chemistry Chemical Physics, 2017, 19, 26240-26247.	2.8	0